

Features

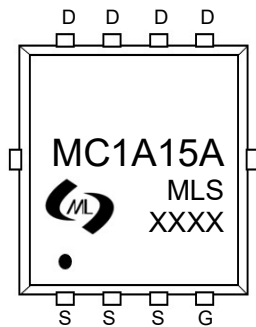
- Super high density cell design for extremely low $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability

Product Summary

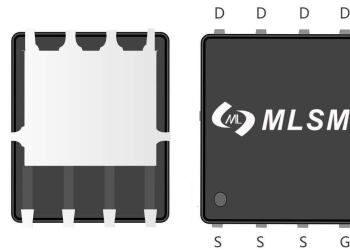
V_{DS}	$R_{DS(ON)}$ MAX	I_D MAX
100V	110mΩ@10V	15A
	120mΩ@4.5V	

Application

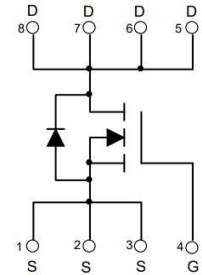
- Power Management in Note book
- DC/DC Converter
- Load Switch
- LCD Display inverter



MC1A15A: Device code
XXXX : Code



PDFN5X6-8L view



Schematic diagram



Halogen-Free

Marking and pin assignment

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings ($T_C=25^{\circ}\text{C}$ Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	100	V
V_{GS}	Gate-Source Voltage	± 20	V
T_J	Maximum Junction Temperature	150	$^{\circ}\text{C}$
T_{STG}	Storage Temperature Range	-50 to 155	$^{\circ}\text{C}$
I_S	Diode Continuous Forward Current	15	A

Mounted on Large Heat Sink

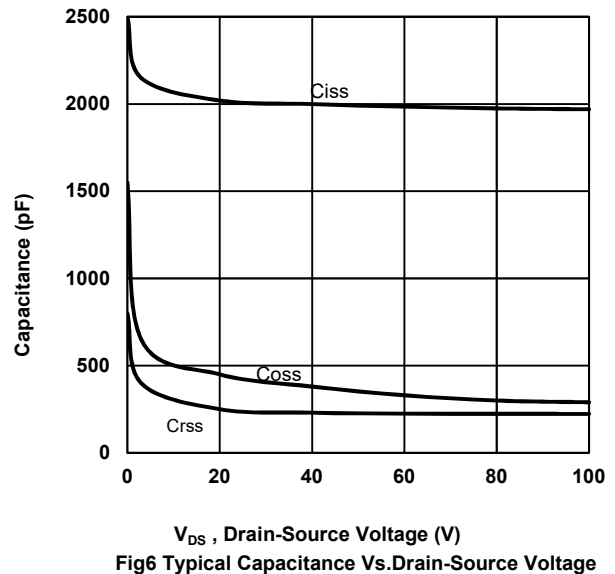
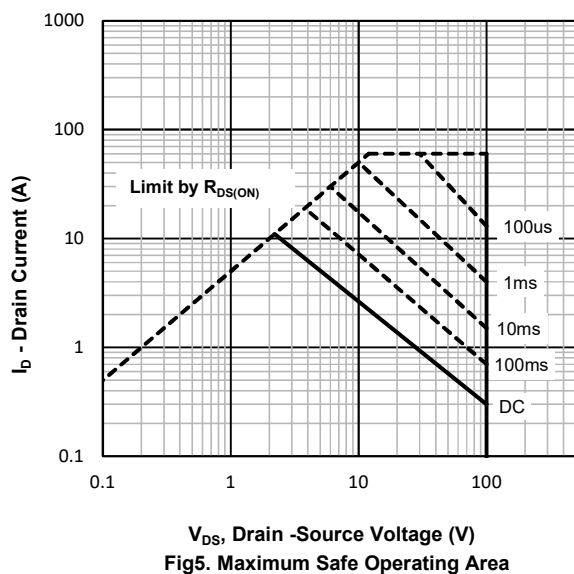
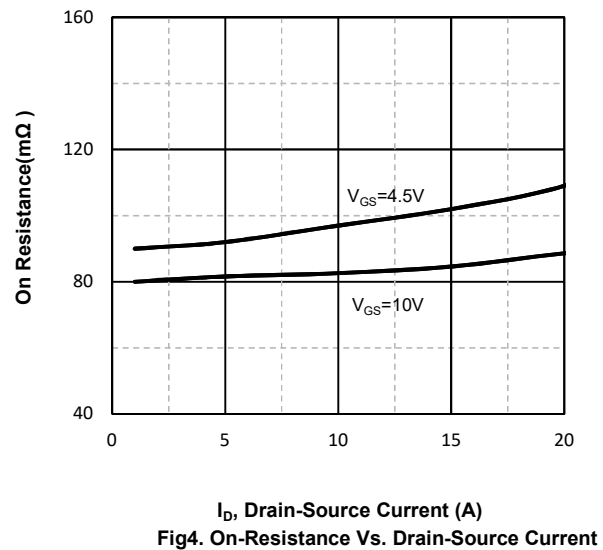
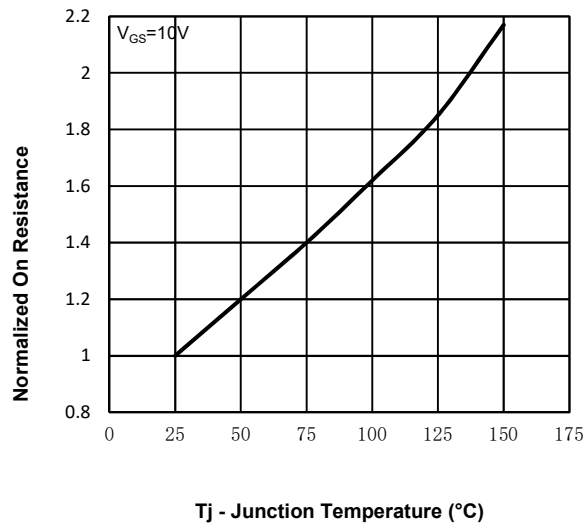
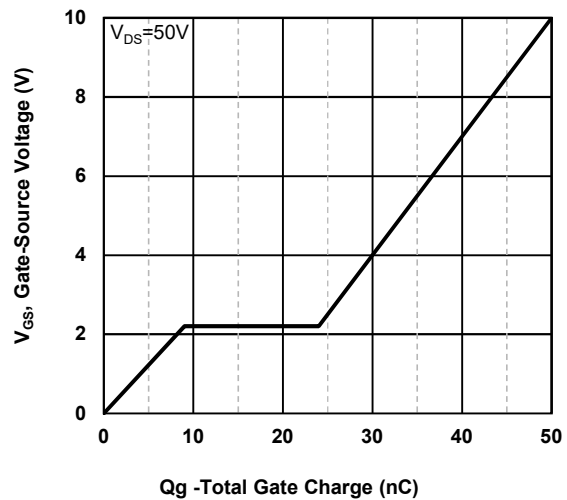
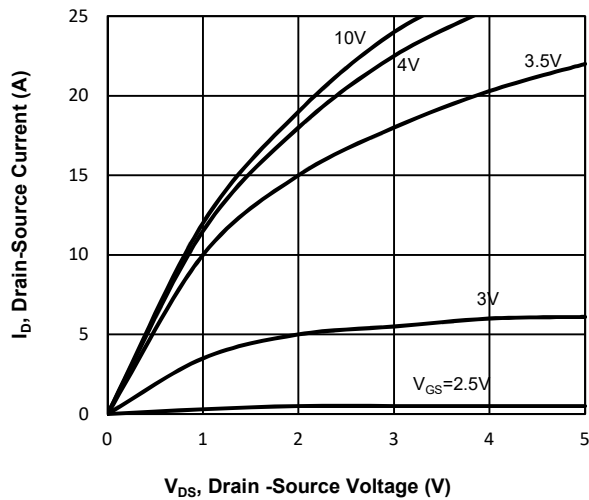
I _{DM}	Pulse Drain Current Tested		60	A
I _D	Continuous Drain Current	T _C =25°C	15	A
P _D	Maximum Power Dissipation	T _C =25°C	25	W
R _{θJA}	Thermal Resistance Junction-Ambient		83.3	°C/W

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MC1A15A	PDFN5X6-8L	MC1A15A	5,000	10,000	70,000	13"reel

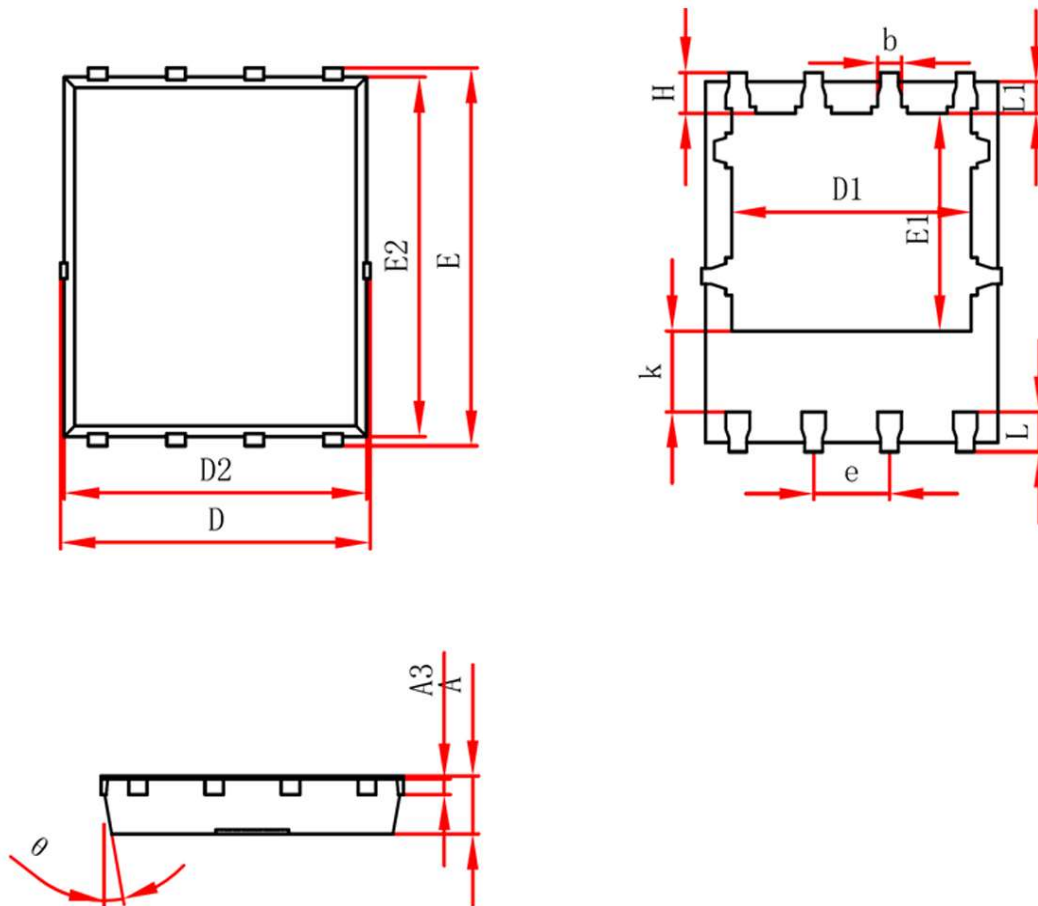
Electrical Characteristics (TJ=25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	100	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =100V, V _{GS} =0V	--	--	1.0	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.3	1.9	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =15A	--	85	110	mΩ
		V _{GS} =4.5V, I _D =8A	--	90	120	mΩ
Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =50V, V _{GS} =0V, f=1MHz	--	1980	--	pF
C _{OSS}	Output Capacitance		--	380	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	250	--	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DD} =50V, I _D =15A, V _{GS} =10V	--	26	--	nC
Q _{gs}	Gate Source Charge		--	5.4	--	nC
Q _{gd}	Gate Drain Charge		--	5.8	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =50V, I _D =15A, V _{GS} =10V, R _G =3Ω	--	7	--	nS
t _r	Turn-on Rise Time		--	24	--	nS
t _{d(off)}	Turn-Off Delay Time		--	25	--	nS
t _f	Turn-Off Fall Time		--	31	--	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	Tj=25°C, Is=15A	--	--	1.2	V

Typical Operating Characteristics





PDFN5X6-8L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.950	1.050	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.950	5.050	0.196	0.200
E	5.950	6.050	0.235	0.239
D1	4.026	4.126	0.159	0.163
E1	3.510	3.610	0.139	0.143
D2	4.850	4.950	0.192	0.196
E2	5.700	5.800	0.225	0.229
k	1.190	1.390	0.047	0.055
b	0.300	0.400	0.012	0.016
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°